

1-Line Uni-directional TVS Diode

Description

The PESDU1201P4-3 is a high power TVS, provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The PESDU1201P4-3 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. This device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi-media card interfaces.

Features

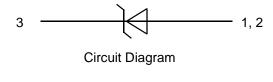
- 5600W peak pulse power (8/20µs)
- Low leakage: nA level
- Operating voltage: 12V
- Ultra low clamping voltage
- · One power line protects
- · Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

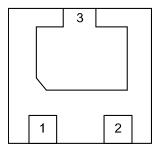
Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 200A (8/20µs)

RoHS Compliant

Dimensions and Pin Configuration





Transparent top view

Mechanical Characteristics

Package: DFN2020-3

Case Material: "Green" Molding Compound

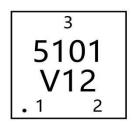
Moisture Sensitivity: Level 1 per J-STD-020

Marking Information: See Below

Applications

- Power Management
- Industrial Application
- Power Supply Protection

Marking Information



5101 V12= Device Making Code

Ordering Information

Part Number	Shipping	Reel Size
PESDU1201P4-3	3000/Tape & Reel	7 inch



Absolute Maximum Ratings (TA=25°C unless otherwise specified)

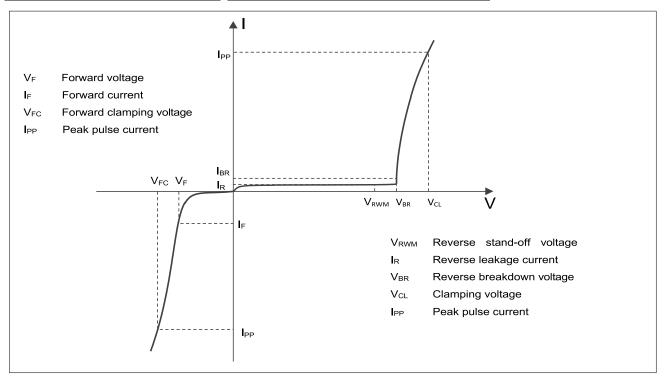
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	P_{PK}	5600	W
Peak Pulse Current (8/20μs)	I _{PP}	200	Α
ESD per IEC 61000-4-2 (Air)	V	±30	kV
ESD per IEC 61000-4-2 (Contact)	V_{ESD}	±30	kV
Lead temperature	TL	260	°C
Operating Temperature Range	Тор	-40 ~ + 85	°C
Storage Temperature Range	T _{STG}	−55 ~ + 150	$^{\circ}$

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			12	V	
Breakdown Voltage	V_{BR}	12.5			V	$I_T = 1 \text{mA}$
Reverse Leakage Current	I _R			1	μA	V _{RWM} = 12V
Clamping Voltage	Vc			25	V	I _{PP} = 150A (8/20µs pulse)
Clamping Voltage	Vc			28	V	I _{PP} = 200A (8/20µs pulse)
Junction Capacitance	CJ		450		pF	V _R = 0V, f = 1MHz



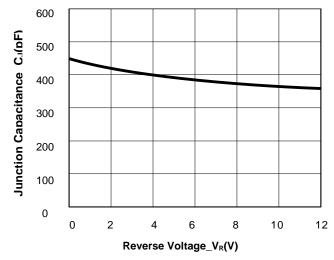
Electrical characteristics (T_A = 25°C, unless otherwise noted)



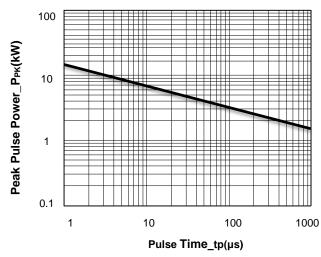
Definitions of electrical characteristics



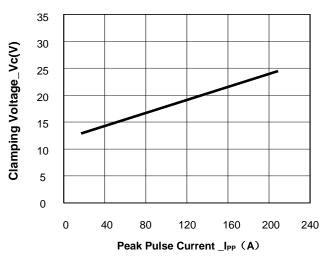
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



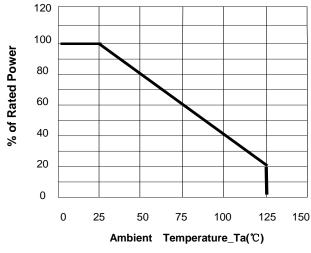
Junction Capacitance vs. Reverse Vlotage



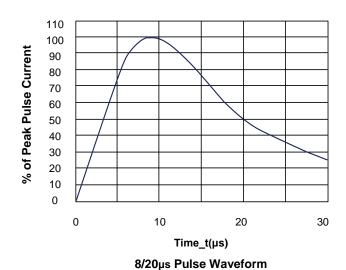
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs.Peak Pulse Current

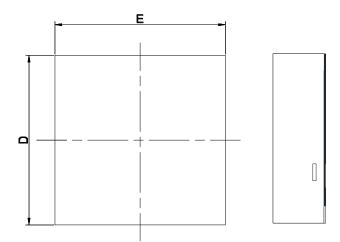


Power Derating Curve

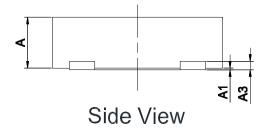




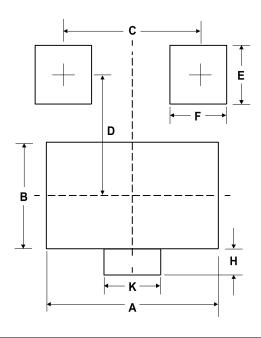
DFN2020-3 Package Outline Drawing

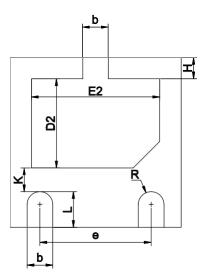


Top View



Suggested Land Pattern





Bottom View

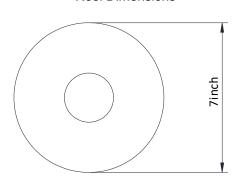
Cymbal	Dimen	sions In Milli	meters
Symbol	Min.	Тур.	Max
Α	0.55	0.60	0.65
A1	0.00	0.02	0.05
А3		0.10 REF.	
b	0.25	0.30	0.35
D	1.90	2.00	2.10
Е	1.90	2.00	2.10
D2	0.95	1.05	1.15
E2	1.40	1.50	1.60
е	1.20	1.30	1.40
Н	0.20	0.25	0.30
K	0.20	0.30	0.40
L	0.35	0.40	0.45
R	0.13	-	-

SYM	MILLIMETERS
А	1.60
В	1.10
С	1.30
D	1.05
Е	0.50
F	0.40
K	0.40
Н	0.25

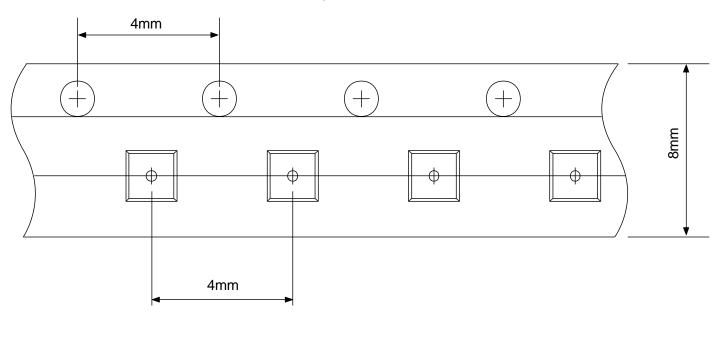


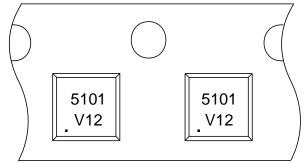
TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions







User Direction of Feed



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